A thermal protection system (TPS) comprising a mixture of silicon carbide and SiO$_x$ that has been converted from Si that is present in a collection of diatom frustules and at least one diatom has quasi-periodic pore-to-pore separation distance $d_{p-p}$ in a selected range. Where a heat shield comprising the converted SiC/SiO$_x$ frustules receives radiation, associated with atmospheric (re)entry, a portion of this radiation is reflected so that radiation loading of the heat shield is reduced.

12 Claims, 7 Drawing Sheets
References Cited

OTHER PUBLICATIONS


* cited by examiner
Cumulative Radiance (CR)
Planck Radiance at T = 9887 deg K (PR)
Atomic Line Radiance at 10 km/sec (ALR)
FIG. 2
n(refractive index; SiC)

Singh et al 1971 - a - SiC: n(\(\phi\)) 0.488-1.064\(\mu\)m

Refractive Index INFO
SiC (Silicon carbide)

Wavelength, \(\mu\)m

FIG. 3A
Refractive Index INFO
SiO₂ (Silicon dioxide, Silica, Quartz)
Malitson 1965 - Fused silica: n 0.21-3.71 μm

FIG. 3B

n(refractive index; SiO₂)

Wavelength, μm
FIG. 5
Heat Shield

Convec. Heating Mode

Convective

Conducted In

Reradiated

Radiative Heating Mode

SL Radiation

Diatoms reflect radiation

Reflected

FIG. 6
I

BIOLOGICALLY INSPIRED RADIATION REFLECTOR

CROSS-REFERENCE TO RELATED APPLICATIONS

This application claims the benefit of U.S. Provisional Application No. 61/930,903, filed Jan. 23, 2014.

ORIGIN OF THE INVENTION

The invention described herein was made in the performance of work under a NASA contract and by employees of the United States Government and is subject to the provisions of Public Law 96-517 (35 U.S.C. § 202) and may be manufactured and used by or for the Government for governmental purposes without the payment of any royalties thereon or therefore. In accordance with 35 U.S.C. § 202, the contractor elected not to retain title.

FIELD OF THE INVENTION

This invention relates to use of innovative materials in a thermal protection system (TPS) for a re-entry vehicle.

BACKGROUND OF THE INVENTION

There is a clear and continuing need for a thermal protection system (TPS) for a re-entering vehicle (RV) that can withstand heating from a high speed entry or re-entry into an atmosphere of a planetary body that is adaptable enough to accommodate human missions and robotic missions. RV surface heating has two primary sources (1) convective heating (proportional to \( (\text{velocity})^3 \)) from flow of hot gases past the surface and from chemical combination reactions in the gases; and (2) radiation heating (approximately proportional to \( \text{velocity}^6 \)) from a shock wave that forms preceding the RV. During high speed initial atmospheric entries, as much as 90 percent of the surface heating can arise through radiation from a reacting shock layer. Where a substantial part of this radiation can be reflected from a heat shield, and prevented from contacting or directed away from the RV surface, the overall heat load can be reduced accordingly, which allows reduced heat shield mass and corresponding greater payload for the re-entrant vehicle. Where a TPS can be developed that withstands a large portion of the convective and radiative heating encountered during a high velocity planetary entry, the risk for a crewed mission is reduced, and shorter transit times and higher re-entry velocities, exceeding 15 km/sec (53,651 mi/hour), can be used.

Radiative heating of an RV and its heat shield peaks early in a re-entry interval into an atmosphere, and this heating often arises from specific, limited ranges of wavelengths of concern, \( \{\lambda_{\text{rad}}\} \), dependent upon atmospheric composition, as indicated in FIG. 1. Provision of a heat shield that has an approximately periodic structure that is preferentially reflective for wavelengths in the range \( \{\lambda_{\text{rad}}\} \) would reduce the fraction of radiation that contacts the RV surface. However, construction of such a heat shield is likely to be expensive and technically demanding. Preferably, the primary heat shield material is refractory and has a high phase change temperature for ablation.

SUMMARY OF THE INVENTION

These needs are met by the invention, which provides a new heat shield material that: (1) is initially a natural material with a quasi-periodic pore sub-structure; and (2) is processed to form a refractory mixture (e.g., SiC and SiO\(_2\)) with superior radiation reflection, phase change and thermal characteristics over the wavelength range \( \{\lambda_{\text{rad}}\} \). The initial natural material is a collection of diatoms, comprising primarily SiO\(_2\) and having pore-to-pore separations \( d \), within an individual diatom, in a selected range D1≤d≤D2 (D1 and/or D2≤100 nm), with particular diatoms preferably chosen for desired diatom pore dimensions. These diatoms react with gaseous Mg at \( T=600^\circ \text{C} \). to form MgO, which is leached from the diatom structure with an acid to form a pure Si frustule. The frustule is then reacted with H\(_2\) and a hydrocarbon gas, such as CH\(_4\) or C\(_2\)H\(_6\) or C\(_3\)H\(_8\), to form a mixture of SiO\(_2\) and SiC (crystalline and/or amorphous), with the degree of crystallinity being estimable by X-ray diffraction. MgO is formed in preference to formation of either of the compounds, MgSi and/or MgSiO\(_3\), which would resist removal of the Mg.

A heat shield material additive, comprising a mixture of SiC and SiO\(_2\) with a quasi-periodic diatom pore structure and prepared in this manner, may have a high phase change temperature (melting, ablation, evaporation, sublimation, etc.), and has a bulk optical reflectivity OR of at least about 0.19 or 0.033 for normal incidence. Incident radiation may also be photonically reflected at much higher values of OR. Other processing details are discussed in a Description of the Invention. The optical reflectivity value OR tends to increase with increasing incidence angle of radiation received at the heat shield component.

The additive may be a continuous layer. Alternatively, the additive is incorporated onto an exposed surface of the substrate heat shield material by impregnation, coating or similar techniques that may produce non-continuous or isolated deposits the additive. This reflecting additive layer would be operate primarily during an initial time interval (e.g., the first 30-60 sec of re-entry).

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 graphically presents an estimate of a radiation spectrum provided by shock layer atomic line radiance (ALR), as a function of wavelength \( \lambda \) for an assumed shock layer temperature \( T(\text{rad};\text{SL})=10,000^\circ \text{C} \), and a corresponding estimated heat shield temperature \( T(\text{rad};\text{HS})=4,000^\circ \text{C} \), in an environment that is initially substantially free of atomic oxygen; FIG. 1 includes, for comparison, a Planck spectrum (PK) of black body radiance and cumulative radiance (CR) for a temperature \( T=4,000^\circ \text{C} \), \( (4273^\circ \text{K}) \).

FIG. 2 schematically illustrates a FBR conversion method used here.

FIGS. 3A and 3B graphically present refractive indices \( n(\lambda;T) \) for SiC and for SiO\(_2\), for visible and mid-infrared wavelengths \( \lambda \).

FIG. 4 indicates graphically a development of temperature adjacent to a temperature at which phase change occurs (melting, ablation, evaporation, sublimation, etc.), according to a conventional view.

FIG. 5 graphically presents an estimation of solution of heat equation for a semi-infinite, one dimensional solid with radiation input at a boundary.

FIG. 6 illustrates reflection/re-radiation that is examined here.

DESCRIPTION OF THE INVENTION.

The invention relies for the initial (natural) material upon diatoms containing diatomite (diatomaceous earth), a sedi-
A fluidized bed reactor (FBR) that can be used for the transformation of the diatom powder to SiC and SiO₂. The FBR includes a quartz reactor vessel that facilitates the three reactions set forth in Eqs. (1), (2) and (3-1) or (3-2) or (3-3). A fluidized powder bed provides an initial reaction site. Reactant gases are received by the bed from a reactant source and passed through the bed, together with a fluidizing gas from a fluidizing source. Heat is provided by a high temperature source. The resulting gases are drawn off through a vent.

Some refinements or modifications to the conversion process include: (1) using lower FBR heating rates and an extended temperature pause at T=640°C. (just below the melt point of Mg, T=650°C) to encourage more complete conversion of Mg to MgO in the first reaction; (2) replacing methane (CH₄) with more reactive, alternative, double bond gases, such as ethylene (C₂H₄) or ethane (C₂H₆) in the third reaction; (3) using a higher concentration of H₂, rather than Ar, in the third reaction, in order to improve distribution of Mg(gas) throughout the FBR, relying on the smaller molecular size of H₂; and (4) providing the FBR with an improved wall liner that resists converting SiO₂ at the wall to Si.

The SiC produced in the third reaction is an α-polytype or a β-polytype, having a melt temperature in a range T(melt)=2650-2730°C. and a sublimation temperature in a range T(sublim)=2,200-2,700°C. Radiation from the shock layer, plus convective heating, is believed to provide heat shield surface temperatures T(rad;HS) as high as 4,000°C. for an RV entering or re-entering a planetary atmosphere at a velocity of 10 km/sec (22,474 mi/hr).

It is not yet known which SiC polytype(s) will be produced by the frustule reactions set forth in the preceding first, second and third reactions. The SiO₂ that may result from the process set forth in Eqs. (1), (2) and (3-1,2,3) has a melt temperature range T(melt)=1600-1725°C. and an evaporation temperature range T(evap)=2230°C.

The Si that may result from the process set forth in Eqs. (1), (2) and (3) has a melt temperature range T(melt)=1414°C. and an evaporation temperature T(evap)=3265°C.

A first estimate of optical reflectivity OR(λ;T) associated with the first sublayer Subl. assumes that all sublimated SiC material is promptly removed from a region adjacent to Subl. and that the local environment comprises a heated first sublayer material with an associated refractive index n_1(λ;T) and a contiguous second layer that is substantially a vacuum, with associated refractive index n=1, as illustrated in FIG. 3A. Assuming that the first layer/second layer interface IF is not too rough, an abrupt change in refractive index at this interface will have an associated optical reflectivity at normal incidence of

\[ OR(λ;T)=\left\{\frac{(n(λ;T)-1)}{(n(λ;T)+1)}\right\}^2, \]  

which has a value of about 0.204 for room temperature SiC and for a wavelength λ~589 nm. This ignores a small difference between ordinary and extraordinary refractive indices, n_0~2.648 and n_0~2.661, of SiC at these conditions.
Estimates of variation of refractive index $n(X;T)$ with wavelength $\lambda$ for bulk SiC, illustrated in FIG. 3A, indicate that the index decreases from about $n(X;T)=2.69$ at $\lambda=500$ nm toward $n(X;T)=2.55$ as wavelength $\lambda$ increases toward and beyond 3000 nm. From examination of FIG. 1, it appears that (1) peak shock layer radiation intensity occurs at a wavelength $\lambda(\text{Planck:peak})=676$ nm for a Planck black body radiation curve, using the Wien displacement law,

$$\lambda(mm)\Gamma(K)=0.00289,$$

with an assumed temperature of $T=4273^\circ$ K. The wavelength range $\{\lambda_{max}\}$ of interest in this situation is approximately 190 nm (vacuum uv)$\lambda_{min}$$\approx3000$ nm so that use of a refractive index, $n(X;T)\approx2.55$, with associated bulk SiC optical reflectivity, $OR(X;T;\text{SiC})=0.19$, appears to be reasonable for modest temperatures.

FIG. 3B graphically illustrates variation of refractive index $n(X;T;\text{SiO}_x)$ with wavelength for a wavelength range of interest here. Where $\text{SiO}_x$ is the bulk material, assuming that the first block/second block interface IF is not too rough, an abrupt change in refractive index of $\text{SiO}_x$ at $\lambda=589$ nm will have an associated optical reflectivity at normal incidence, according to Eq. (4), of $OR(X;T;\text{SiO}_x)=0.034$. The refractive index $n(X;T;\text{SiO}_x)$ and the optical reflectivity $OR(X;T;\text{SiO}_x)$ will decrease further as wavelength increases toward and beyond $\lambda=3000$ nm.

Example: Some Optimal Choices of Diatom Parameters.

The optical reflectivity $OR(X;T)$ of a block of material (not removed) may be enhanced by choosing a diatom species with nearest neighbor pore separation distances $d(p-p)$ (measured laterally) having selected values that are approximately equal to optimal values estimated in the technical literature. For example, in N. Komarevskiy et al., “Potential of glassy carbon and silicon carbide photonic refractive layer in a wavelength range $X-7200-1400$ nm, which lie in a relevant radiation wavelength range, and with other parameters so that the examples given here, $d(p-p)=226, 229, 230$ and 239 nm (each no more than 300-400 nm), will change according to the physical and geometric situation. Within an individual diatom, the pore-to-pore separation distances $d(p-p)$ will not be precisely the same so that the arrangement of pores will be quasi-periodic rather than strictly periodic. However, from the variety of diatoms available, it is possible to identify and use one or more species with approximately the same (optimal) pore-to-pore separation distances $d(p-p)$.

First Model: SiC/$\text{SiO}_x$ Layer Located at Exposed Surface of Heat Shield.

In a first model, the transformed diatom material (SiC or $\text{SiO}_x$) is provided as a coating or first sub-layer $\text{SubL}$, located at an exposed surface of the heat shield, and experiences an estimated maximum temperature, from shock layer radiation and convective heating, $T(\text{rad:max})=4000^\circ$ C. This maximum HS surface temperature subsequently decreases to lower temperatures over the next 30-60 sec. A first portion of the first sub-layer undergoes phase change in this environment and is treated here as providing no substantial contribution to reflection of radiation received from the shock layer SL. A second (remaining) portion of the first sub-layer is assumed to be intact and to have sufficient (remaining) longitudinal thickness $\Delta t$ to provide an associated optical reflectivity, $OR(X;T;\text{SiO}_x)>0.19$ or 0.033, for this second (remaining) portion of the first sub-layer $\text{SubL}_2$ of lower bound on an initial longitudinal thickness $\Delta t(\text{min})$ of the first sub-layer $\text{SubL}_1$ can be estimated by the following considerations. Assume that the shock layer radiation power density $P(\text{rad})=\text{kw/m}^2$ is approximately constant or decreasing with time, where $E(t)$ is cumulative energy deposited. This power density is anticipated to decrease overall with passage of time, after an initial (re)entry time interval, because the velocity of the re-entry vehicle RV will decrease as the RV moves through the atmosphere.

Phase change of a volume $\Delta V$ of SiC or $\text{SiO}_x$ requires provision of at least the following radiant energy: (i) a first energy density component $\Delta E1$ that is required to raise the volume $\Delta V$ from a reference temperature value $T(\text{ref})$ to a phase change initiation temperature $T(\text{phase})$, and (ii) a second measure of energy input $\Delta E2$ required to convert the volume $\Delta V$ of initially solid SiC or $\text{SiO}_x$ material at temperature $T(\text{phase})$ to material that has undergone a phase change. With reference to FIG. 4, below and near a phase change temperature $T(\text{phase})$, the temperature of a material increases to $T(\text{phase})$, then appears to plateau at $T=T(\text{phase})$ after the volume $\Delta V$ has reached the first energy content $\Delta E1$. The apparent temperature remains at a value $T(\text{phase})$, while the volume $\Delta V$ accumulates an additional energy increment $\Delta E2$ required for completion of phase change, after which time the temperature may continue to increase, as indicated in FIG. 4 according to a conventional view. This perspective applies for phase change of a volume of SiC or of $\text{SiO}_x$.

In a first approximation, it is assumed that each of the energy inputs, $\Delta E1$ and $\Delta E2$, is distributed according to a one-dimensional heat equation for energy distribution, $u(x, t)=\text{temperature in a semi-infinite solid with thermal conductivity } k$, specific heat capacity $c$, density $\rho$, which are temperature-independent, through a solid with cross-sectional area $A$ oriented perpendicular to a direction of transport of temperature.

$$\frac{\partial^2 u}{\partial x^2}=(1/k)\frac{\partial u}{\partial t}\text{ at }x=\infty$$

(6)

$$k=pc\lambda,\text{ at }x=0,\text{ and }$$

(7)

$$u(x, t-0)=u(0),\text{ at }x=0$$

(8)

$$\text{at }x=\infty$$

(9)
Here, the solid is initially at temperature $u=0$ and is heated by radiation from a source at temperature $u_0$. One solution for this formulation is set forth by H.S. Carslaw and J.C. Jaeger in *Conduction of Heat in Solids*, Oxford Press, 1946, pp. 70-73:

$$v(x,t) = -v(x) = 0 - u_0 e^{-x^2/(2Kt)} - e^{-x^2/(2Kt)} \text{erfc}(x/\sqrt{2Kt})$$

$$v(x) = 0 - u_0 e^{-x^2/(2Kt)} - e^{-x^2/(2Kt)} \text{erfc}(x/\sqrt{2Kt})$$

Adjacent to the boundary, $x=0$, the radiation energy deposit in a volume $AV$ corresponds to Eq. (9), and the heat energy continues to rise at and near this boundary as long as heat transfer across this boundary continues. FIG. 5, adapted from FIG. 9, page 72 of Carslaw and Jaeger, ibid., graphically presents a sequence of curves providing estimates of temperature $u(x,t)/u_0$ corresponding to constant values of a dimensionless coordinate, $s=x/\sqrt{4Kt}$:

$$s = \frac{x}{\sqrt{4Kt}} >_{0.1, 0.2, 0.3}$$

When the local heat energy $(pc)u(x,t)$ reaches a value $AE1$, the temperature in a local volume $AV$ has reached a first value at which the phase change process begins. However, the local heat energy $(pc)u(x,t)$ must reach an energy value, $AE1+AE2$, in order to complete the phase change process in the local volume $AV$. This analysis will focus primarily on the total energy, $AE1+AE2$, required to complete the phase change process in the local volume $AV$.

**Phase change is initiated for a portion of the solid, given by the condition**

$$(s(x=\text{thr};1)) = x(\text{thr};AE1)$$

for which the corresponding heat energy satisfies

$$(pc)u(x=\text{thr};1), (\text{AE1})$$

**Phase change, once begun, is completed for a portion of the solid defined by condition**

$$(s(x=\text{thr};2)) = x(\text{thr};AE1+AE2)$$

for which the corresponding heat energy satisfies

$$(pc)u(x=\text{thr};2), (\text{AE1+AE2})$$

The model of phase change represented in FIG. 4 is implemented as follows. For a fixed coordinate value $x(x_0)$ and variable time value $t$, a measure of heat energy, $(pc)u(x,t)$, satisfies $(pc)u(x,t) < AE1+AE2$ until time $t$ reaches a threshold value $t$:

$$t(\text{thr}) = t(\text{AE1}+\text{AE2})$$

$$t(\text{thr}) = t(\text{AE1}+\text{AE2})$$

where the threshold time value $t(x;AE1+AE2)$ corresponds to completion of phase change at that value of the coordinate $x$, and $t(x;AE1+AE2)$ increases monotonically with increasing $x$.

In FIG. 5, a horizontal line $H-H$, corresponding to an arbitrary fraction $\psi = u/u_0 = 0.7$ of the maximum heat energy value, $(pc)u(x=0,t)$ present in a volume $AV$, is shown for the normalized temperature $u_0$. The line $H-H$ indicates that, for values of the dimensionless coordinate $s=x/\sqrt{4Kt}$ greater than $s_{\text{max}} = 0.27$, a volume $AV$ located at the corresponding coordinate pair $(x,t)$ cannot attain or exceed the corresponding normalized temperature, $\psi(u) = u_0 = 0.7$. Where the fraction $\psi = 0.7$ is interpreted as corresponding to achievement of complete phase change, a volume $AV$, located at a coordinate $x$ corresponding to $s_{\text{max}} = 0.27$, cannot (yet) complete the phase change. The numerical value of the fraction $\psi$ of maximum heat energy actually chosen will depend upon the power density value provided by the shock layer radiation and upon the total energy, $AE1+AE2$, required for completion of phase change for the volume $AV$. The portion of the solid for which the phase change process is completed may pass away as a gas or vapor so that an initial thickness value $\tau$ of the SiC or SiO$_2$ material will decrease as time increases.

Assume that an initial thickness, defined by $\psi(\text{thr})$, of the SiC or SiO$_2$ material is provided at an exposed surface of the heat shield HS for the re-entering vehicle RV and that one wishes to ensure that a portion of this SiC or SiO$_2$ thickness, which is decreasing with passage of time because of phase change, will survive and not disappear during a re-entry survival time interval, $0 < t < t(\text{surv})$. Completion of phase change for a volume $AV$ (heat energy $AE1+AE2$) is assumed to correspond to a fraction $\psi = 0$ for the dimensionless quantity $u_0$ in the sequence of curves presented in FIG. 5. A horizontal line, $\psi = 0$ is drawn in FIG. 5, and a survival value,

$$s(\text{surv}) = x(\text{thr};\text{surv})$$

of the dimensionless variable $s$ is computed and compared with the horizontal line $\psi = 0$ in FIG. 5. Where the value $s(\text{surv})$ lies above the horizontal line, $\psi = 0$, in a graph corresponding to FIG. 5, a portion of the initial thickness, $0 < x_0$, of the SiC or SiO$_2$ material will survive the phase change process for (at least) a survival time interval length $t(\text{surv})$. The portion of the thickness $\tau$ that does not survive the phase change process serves as a sacrificial layer. The fractional value, $\psi = 0$, used here may be used as a zeroth order estimate of optical reflectivity OR for this model.

Where the survival value $s(\text{surv})$ lies on or below the horizontal line, $\psi = 0$, in a graph corresponding to FIG. 5, no portion of the initial thickness, $0 < x_0$, of the SiC or SiO$_2$ material will survive. When the SiC or SiO$_2$ material thickness has decreased below a minimum thickness $\tau(\text{photonic})$, dependent upon a representative wavelength $\lambda_{\text{photonic}}$ of the incident radiation, optical reflectivity OR from this remaining layer will likely decrease toward 0.

**Second Model: SiC/SiO$_2$ Material Deposited in Isolated Clusters at Exposed Surface of Heat Shield.**

In a second model, the SiC and/or SiO$_2$ material is deposited in isolated clusters at an exposed surface of another heat shield component on an RV, through impregnation or other deposit process. Each cluster of the SiC and/or SiO$_2$ deposits has a numerical differential area $\Delta A_j$ ($j=1, \ldots , J$), which is assumed to be at least equal to a threshold value $\Delta A(\text{thr})$ required for reflection. The sum

$$\Delta A = \sum_{j=1}^{J} \Delta A_j$$

is a fraction $f$ ($0 < f < 1$) of the total projected area $A$ of the exposed surface.

A diatom within each of these deposits of transformed diatom material may be treated as comprising a quasi-periodic array of pores that approximately supports reflection of the incident radiation, with an associated optical reflectivity OR($j$) that lies between a lower bound, OR(bulk; SiC) = 0.19 or OR(bulk;SiO$_2$) = 0.033, and a much higher upper bound, OR(photonic), that would be provided by photonic interaction of the incident radiation with a quasi-periodic pore structure. An estimate of overall optical reflectivity for the exposed surface (area $A$) of the heat shield then becomes
Conclusion.

The invention disclosed here incorporates diatom material, transformed or converted into SiC and/or SiO₃, as an additive in a heat shield component in order to enhance the thermal protection characteristics in at least one of two ways: (1) increasing temperatures or heat content required for phase change of the material and enhancing refractory behavior of the material; and (2) enhancing photonic behavior and reflection of radiation received by the shield from a shock layer that forms as the RV enters or re-enters the atmosphere of a planetary body. The pore structure within a diatom is quasi-periodic, and an average nearest neighbor pore-to-pore separation distance d(p-p) is preferably chosen to be approximately equal to one or more of the estimated optimal periodicity dimensions. The heat content received by the heat shield and its additive comprises radiation from a shock layer that forms upon RV entry or re-entry and convective heating produced by motion of the RV.

The additive provides (i) enhanced reflection of the radiation of wavelengths in a range that corresponds to wavelengths of the incident radiation and (ii) re-radiation of the convective heating received, at wavelengths that are generally larger than the range of wavelengths that are associated with convective heating. A primary goal is to reduce substantially the convective and radiation heat content that is ultimately absorbed by the heat shield and additive. The diatom material that is processed to provide the additive is initially a naturally occurring material with a quasi-periodic pore structure within each diatom. The reflection of radiation in an associated wavelength range and re-radiation of wavelengths in another (convective heating) range are separately illustrated in FIG. 6.


Diatoms are unicellular, eukaryotic, mostly photosynthetic micro-organisms that possess exoskeletons (frustules) comprising amorphous silica (SiO₂). Each diatom is bounded by a frustule or cell wall of silica (hydrated SiO₂), including two valves of slightly different size that fit together in a connective zone, known as a girdle, and enclose the remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom. Diameters of the diatoms lie in a range 2-2,000 µm; some species can be seen with an unaided remainder of a diatom.

Three porous layers of silica are present, and the pore distribution is approximately radially symmetric for Coscinodiscus sp. For the T. eccentrica diatom, the corresponding dimensions were

\[
d(pore)=45±9 \text{ nm},
\]
\[
porosity=7.5±1.2\%,
\]
\[
d(p-p)=310 \text{ nm (estimate)}.\]

For T. eccentic, two porous layers of silica are present, and the pore distribution is approximately linear (row upon row, referred to as "concentric"), rather than radially symmetric. Pore-to-pore separation distances within an individual diatom can be as large as about 2 µm.

What is claimed is:

1. A method for providing a thermal protection component for a space vehicle that enters or re-enters an atmosphere, the method comprising:

(1) providing a plurality of particles, comprising Mg, and a powder bed of frustules of SiO₂ (x=1) from diatom shells in a heated fluidized bed reactor (FBR), where at researchers converted all silica in a diatom into magnesium oxide MgO. In another experiment, reported in 2004, a diatom was exposed to titanium dioxide TiO₂, which completely replaced the silica in the diatom.

Diatoms are traditionally divided into two orders: Centrales or centric diatoms have pores or apertures that are distributed approximately radially symmetric; and Pennat diatoms have pores or apertures that are distributed approximately bilaterally symmetric. Diatoms of the same species consistently form shells or frustules with the same pattern, which may indicate that the designs are genetically programmed. Frustules of a diatom will usually have pores or apertures, often with pore diameter values d(pore) of about 40 nm, but with nearest neighbor pore separation distances d(p-p) that have a larger range. The limited range of pore diameters d(pore) allows diatom frustules to be used for particle sorting and separation.

Diatoms are traditionally divided into two orders: Centrales or centric diatoms have pores or apertures that are distributed approximately radially symmetric; and Pennat diatoms have pores or apertures that are distributed approximately bilaterally symmetric. Diatoms of the same species consistently form shells or frustules with the same pattern, which may indicate that the designs are genetically programmed. Frustules of a diatom will usually have pores or apertures, often with pore diameter values d(pore) of about 40 nm, but with nearest neighbor pore separation distances d(p-p) that have a larger range. The limited range of pore diameters d(pore) allows diatom frustules to be used for particle sorting and separation.

Centers of diatom pores appear to be distributed in an approximately hexagonal pattern. Assuming that a regular hexagon pattern is precisely repeated, with a uniform center-to-center separation distance d(p-p) = 2d₁, each hexagon is the sum of 12 30-60-90 triangles with hypotenuse length (2d₁)/√3 and has an area

\[
A(\text{hex})=(6 \sqrt{3}/4) d₁² = \frac{3 \sqrt{3}}{2} d₁²
\]

Where a single pore of radius d₂ is located within this hexagon, the porosity fraction associated with this pattern has a value

\[
\text{porosity}=(\pi \sqrt{3}/6)(d₁/d₂)^2 \leq (d₁/d₂)^2
\]

A hydrofluoric acid (HF) solution can be used to increase the pore diameters d(pore) for a given diatom. It is unclear what effect, if any, an HF treatment has on the pore-to-pore separation distance d(p-p).

D. Losic et al, in "Pore Architecture of Diatom Frustules" Jour. Of Nanoscience and Nanotechnology, Vol. 6 (2006) pp 1-8, have measured frustule dimensions statistically for two species, Coscinodiscus sp. and Thalassiosira eccentrica. For the Coscinodiscus sp., average pore diameter, average pore-to-pore distance and average porosity value were

\[
d(pore)=45±9 \text{ nm},
\]
\[
porosity=7.5±1.2\%,
\]
\[
d(p-p)=310 \text{ nm (estimate)}.\]
least one diatom shell has average nearest neighbor pore-to-pore spacing \( d(p-p) \) that lies in a selected range,
\( D_1 < d(p-p) < D_2 \), with \( D_{12} = 100 \text{ nm} \) and \( D_{22} = 400 \text{ nm} \);
2. heating the plurality of particles and the \( \text{SiO}_2 \) powder bed to a first temperature no greater than about \( 800^\circ \text{C} \), and allowing at least a portion of the particles and the \( \text{SiO}_2 \) powder bed to react to form \( \text{MgO} \) and \( \text{Si} \);
3. leaching \( \text{MgO} \) to provide a first mixture comprising \( \text{Si} \) particles and \( \text{SiO}_2 \) particles;
4. providing a hydrocarbon gas, comprising at least one of \( \text{C}_1 \) to \( \text{C}_2 \) \( \text{H}_4 \) and \( \text{C}_2 \) \( \text{H}_6 \), plus an \( \text{H}_2 \) gas in the FBR in a temperature range \( T_2 = 640-800^\circ \text{C} \);
5. allowing the first mixture comprising \( \text{Si} \) particles and \( \text{SiO}_2 \) particles to react with the hydrocarbon gas and with the \( \text{H}_2 \) gas in the FBR to form a substance comprising \( \text{SiC} \) and \( \text{SiO}_2 \), wherein at least a portion of the first mixture is converted to a second mixture comprising \( \text{SiC} \) and \( \text{SiO}_2 \) particles, wherein a temperature during the reaction of the first mixture with the hydrocarbon gas and with the \( \text{H}_2 \) gas in the FBR is no higher than \( 800^\circ \text{C} \);
6. providing a layer of the second mixture, having an initial thickness \( t_1 \) at least equal to a selected threshold thickness \( t_1(\text{thr}) \), on an exposed surface of a heat shield system;
7. permitting the layer of the second mixture to receive radiation from a source of radiation; and
8. permitting the layer of the second mixture to serve as an optical reflector to reflect a portion of the radiation received.

2. The method of claim 1, further comprising choosing said pore-to-pore spacing \( D_{12} = 200 \text{ nm} \).
3. The method of claim 1, further comprising choosing said pore-to-pore spacing \( D_{22} = 300 \text{ nm} \).
4. The method of claim 1, wherein said hydrocarbon gas contains \( \text{C}_2 \) \( \text{H}_4 \), \( \text{C}_2 \) \( \text{H}_6 \), or a combination thereof.
5. The method of claim 1, further comprising limiting said first temperature to a range, \( T_1 = 600-640^\circ \text{C} \).
6. The method of claim 1, further comprising choosing said threshold thickness \( t_1(\text{thr}) \) that is sufficient so that, after exposure of said second mixture to said radiation for a selected time interval length \( \Delta t \), a portion of said second mixture remains on said exposed surface.
7. A method for providing a thermal protection component for a space vehicle that enters or re-enters an atmosphere, the method comprising:
8. The method of claim 7, further comprising choosing said pore-to-pore spacing \( D_{12} = 200 \text{ nm} \).
9. The method of claim 7, further comprising choosing said pore-to-pore spacing \( D_{22} = 300 \text{ nm} \).
10. The method of claim 7, wherein said hydrocarbon gas contains \( \text{C}_2 \) \( \text{H}_4 \), \( \text{C}_2 \) \( \text{H}_6 \), or a combination thereof.
11. The method of claim 7, further comprising limiting said first temperature to a range, \( T_1 = 600-640^\circ \text{C} \).
12. The method of claim 7, further comprising choosing said threshold thickness \( t_1(\text{thr}) \) that is sufficient so that, after exposure of said second mixture to said radiation for a selected time interval length \( \Delta t \), a portion of said second mixture remains on said exposed surface.